## Renesas

## 2SC4995

## Silicon NPN Epitaxial

REJ03G0194-0300Z
(Previous ADE-208-013A (Z) )
Rev.3.00
Apr.05.2004

## Application

VHF / UHF wide band amplifier

## Features

- High gain bandwidth product
$\mathrm{f}_{\mathrm{T}}=11 \mathrm{GHz}$ Typ.
- High gain, low noise figure
$\mathrm{PG}=16.5 \mathrm{~dB}$ Typ. , NF $=1.1 \mathrm{~dB}$ Typ. at $\mathrm{f}=900 \mathrm{MHz}$


## Outline

## CMPAK-4



1. Collector
2. Emitter
3. Base
4. Emitter

Note: Marking is "YD-".

Attention: This device is very sensitive to electro static discharge.
It is recommended to adopt appropriate cautions when handling this transistor.

## Absolute Maximum Ratings

|  |  |  | Symbol |
| :--- | :--- | :--- | :--- |
| Item | Ratings | Unit |  |
| Collector to base voltage | $\mathrm{V}_{\text {CBO }}$ | 15 | V |
| Collector to emitter voltage | $\mathrm{V}_{\text {CEO }}$ | 8 | V |
| Emitter to base voltage | $\mathrm{V}_{\text {EBO }}$ | 1.5 | V |
| Collector current | $\mathrm{IC}_{\mathrm{C}}$ | 50 | mA |
| Collector power dissipation | $\mathrm{P}_{\mathrm{C}}$ | 100 | mW |
| Junction temperature | Tj | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | Tstg | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

## Electrical Characteristics

| Item | Symbol | Min | Typ | Max | Unit | $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$ <br> Test Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector to base breakdown voltage | $\mathrm{V}_{\text {(BR)CBO }}$ | 15 | - | - | V | $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0$ |
| Collector cutoff current | $\mathrm{I}_{\text {Cbo }}$ | - | - | 10 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{CB}}=12 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0$ |
|  | ICEO | - | - | 1 | mA | $\mathrm{V}_{\mathrm{CE}}=8 \mathrm{~V}, \mathrm{R}_{\mathrm{BE}}=\infty$ |
| Emitter cutoff current | $\mathrm{I}_{\text {ebo }}$ | - | - | 10 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{EB}}=1.5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$ |
| DC current transfer ratio | $\mathrm{h}_{\text {FE }}$ | 50 | 120 | 250 |  | $\mathrm{V}_{C E}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}$ |
| Collector output capacitance | Cob | - | 0.55 | 1.1 | pF | $\mathrm{V}_{C B}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1 \mathrm{MHz}$ |
| Gain bandwidth product | $\mathrm{f}_{\mathrm{T}}$ | 8.0 | 11.0 | - | GHz | $\mathrm{V}_{C E}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}$ |
| S21 Parameter | \|S21| | - | 16 |  | dB | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}, \\ & \mathrm{f}=1000 \mathrm{MHz} \end{aligned}$ |
| Power gain | PG | 13.5 | 16.5 |  | dB | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}, \\ & \mathrm{f}=900 \mathrm{MHz} \end{aligned}$ |
| Noise figure | NF |  | 1.1 | 2.0 | dB | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=5 \mathrm{~mA}, \\ & \mathrm{f}=900 \mathrm{MHz} \end{aligned}$ |

## Main Characteristics






S Parameter

| Freq. <br> (MHz) | S11 |  | S21 |  | S12 |  | $\left(\mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=5 \mathrm{~mA}, \mathrm{Z}_{\mathrm{O}}=50 \Omega\right)$ |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | S22 |  |  |  |
|  | MAG. | ANG. |  |  | MAG. | ANG. | MAG. | ANG. | MAG. | ANG. |
| 200 | 0.781 | -48.2 | 12.84 | 148.8 | 0.0449 | 64.6 | 0.866 | -28.6 |
| 400 | 0.669 | -83.6 | 10.04 | 127.3 | 0.0695 | 50.3 | 0.682 | -46.9 |
| 600 | 0.591 | -109.4 | 7.84 | 113.9 | 0.0815 | 42.6 | 0.541 | -58.1 |
| 800 | 0.549 | -129.1 | 6.30 | 104.4 | 0.0889 | 39.2 | 0.446 | -65.2 |
| 1000 | 0.524 | -145.0 | 5.23 | 96.7 | 0.0937 | 38.4 | 0.381 | -70.4 |
| 1200 | 0.520 | -156.8 | 4.45 | 90.7 | 0.0986 | 37.7 | 0.340 | -74.6 |
| 1400 | 0.515 | -166.9 | 3.86 | 86.0 | 0.103 | 38.7 | 0.309 | -77.7 |
| 1600 | 0.518 | -176.0 | 3.44 | 81.1 | 0.107 | 40.0 | 0.287 | -81.2 |
| 1800 | 0.523 | 176.5 | 3.11 | 77.3 | 0.111 | 41.2 | 0.268 | -85.1 |
| 2000 | 0.537 | 170.1 | 2.82 | 73.5 | 0.116 | 42.4 | 0.256 | -89.0 |

S Parameter
$\left(\mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}, \mathrm{Z}_{\mathrm{O}}=50 \Omega\right)$

| F <br> Freq. <br> (MHz) | S11 |  | S21 |  | S12 |  | S22 |  |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
|  | MAG. | ANG. | MAG. | ANG. | MAG. | ANG. | MAG. | ANG. |
| 200 | 0.542 | -69.9 | 24.74 | 128.7 | 0.0296 | 55.5 | 0.631 | -52.5 |
| 400 | 0.520 | -136.2 | 15.31 | 109.4 | 0.0398 | 50.2 | 0.395 | -72.9 |
| 600 | 0.516 | -156.3 | 10.81 | 99.5 | 0.0470 | 52.8 | 0.285 | -83.6 |
| 800 | 0.519 | -169.1 | 8.29 | 93.5 | 0.0547 | 55.1 | 0.225 | -91.3 |
| 1000 | 0.525 | -179.2 | 6.70 | 88.5 | 0.0624 | 57.9 | 0.189 | -97.5 |
| 1200 | 0.538 | 173.6 | 5.63 | 84.1 | 0.0712 | 60.2 | 0.166 | -102.8 |
| 1400 | 0.540 | 167.5 | 4.85 | 80.9 | 0.0805 | 61.5 | 0.151 | -107.9 |
| 1600 | 0.554 | 161.6 | 4.29 | 77.5 | 0.0895 | 62.8 | 0.140 | -112.6 |
| 1800 | 0.567 | 159.5 | 3.86 | 74.3 | 0.0991 | 63.8 | 0.134 | -118.1 |
| 2000 | 0.580 | 151.7 | 3.48 | 71.6 | 0.109 | 64.3 | 0.129 | -122.5 |

S Parameter

|  |  |  |  |  |  | $\left(\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=5 \mathrm{~mA}, \mathrm{Z}_{\mathrm{O}}=50 \Omega\right)$ |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| Freq. <br> (MHz) | S11 | MAG. | ANG. | MAG. | ANG. | MAG. | ANG. | MAG. |
|  | S22 | ANG. |  |  |  |  |  |  |
| 200 | 0.739 | -65.4 | 11.99 | 140.8 | 0.0681 | 56.9 | 0.793 | -44.9 |
| 400 | 0.643 | -106.5 | 8.54 | 118.9 | 0.0957 | 41.5 | 0.576 | -72.1 |
| 600 | 0.603 | -132.0 | 6.34 | 106.4 | 0.107 | 34.9 | 0.446 | -89.4 |
| 800 | 0.586 | -148.7 | 4.99 | 97.9 | 0.114 | 32.6 | 0.369 | -101.9 |
| 1000 | 0.578 | -162.1 | 4.08 | 90.9 | 0.118 | 32.6 | 0.323 | -112.0 |
| 1200 | 0.580 | -171.9 | 3.45 | 86.0 | 0.124 | 32.7 | 0.396 | -120.1 |
| 1400 | 0.588 | 179.9 | 2.99 | 81.7 | 0.129 | 33.3 | 0.275 | -127.0 |
| 1600 | 0.596 | 172.9 | 2.67 | 77.2 | 0.134 | 34.3 | 0.263 | -133.0 |
| 1800 | 0.607 | 166.8 | 2.41 | 73.4 | 0.139 | 35.9 | 0.256 | -139.5 |
| 2000 | 0.617 | 161.0 | 2.20 | 70.0 | 0.145 | 36.9 | 0.254 | -144.7 |

S Parameter
$\left(\mathrm{V}_{\mathrm{CE}}=1 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}, \mathrm{Z}_{\mathrm{O}}=50 \Omega\right)$

| F <br> Freq. <br> (MHz) | S11 |  | MAG. | ANG. | MAG. | ANG. | MAG. | ANG. |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| 200 | 0.588 | -127.7 | 19.25 | 119.0 | 0.0389 | 47.2 | MAG. | ANG. |
| 400 | 0.618 | -157.6 | 11.00 | 102.5 | 0.0483 | 45.3 | 0.380 | -86.7 |
| 600 | 0.627 | -171.4 | 7.62 | 94.6 | 0.0570 | 49.0 | 0.334 | -130.8 |
| 800 | 0.639 | 179.6 | 5.80 | 89.2 | 0.0662 | 52.6 | 0.315 | -150.9 |
| 1000 | 0.650 | 172.1 | 4.66 | 84.5 | 0.0768 | 55.9 | 0.306 | -158.9 |
| 1200 | 0.656 | -166.4 | 3.94 | 81.1 | 0.873 | 57.7 | 0.302 | -165.4 |
| 1400 | 0.664 | 160.7 | 3.40 | 78.2 | 0.0996 | 59.2 | 0.301 | -170.5 |
| 1600 | 0.677 | 156.5 | 3.03 | 75.2 | 0.110 | 60.2 | 0.301 | -174.6 |
| 1800 | 0.689 | 151.6 | 2.71 | 71.9 | 0.122 | 61.1 | 0.304 | -178.4 |
| 2000 | 0.696 | 147.5 | 2.47 | 69.2 | 0.134 | 61.2 | 0.306 | 178.2 |

## Package Dimensions



## Ordering Information

| Part Name | Quantity | Shipping Container |
| :--- | :--- | :--- |
| 2 SC 4995 | 3000 pcs | $\phi 178 \mathrm{~mm}$ Taping Reel (TL) |

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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